

Switching diode

• Applications

High speed switching

• Features

- 1) Small surface mounting type.
- 2) High Speed.(trr =1.2ns Typ.)
- 3) High reliability with high surge current handling capability.
- 4) We declare that the material of product compliance with RoHS requirements.

• Construction

Silicon epitaxial planar

• Device Marking and Ordering Information

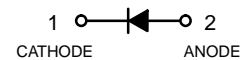
Device	Marking	Shipping
L1SS355T1G	5D	3000/Tape&Reel
L1SS355T3G	5D	10000/Tape&Reel

• Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V _{RM}	90	V
DC reverse voltage	V _R	80	V
Peak forward current	I _{FM}	225	mA
Mean rectifying current	I _O	100	mA
Surge current (1s)	I _{surge}	500	mA
Junction temperature	T _J	125	°C
Storage temperature	T _{stg}	-55~+125	°C

• Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditons
Forward voltage	V _F	-	-	1.2	V	I _F =100mA
Reverse current	I _R	-	-	0.1	μA	V _R =80V
Capacitance between terminals	C _T	-	-	3.0	pF	V _R =0.5V, f=1MHz
Reverse recovery time	t _{rr}	-	-	4	ns	V _R =6V, I _F =10mA, R _L =100Ω



L1SS355T1G

• Electrical characteristic curves (Ta=25°C)

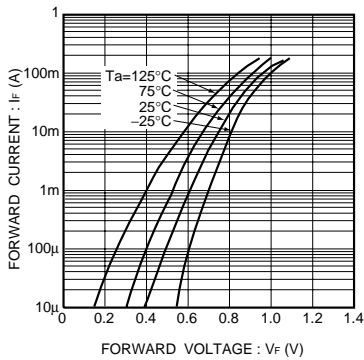


Fig.1 Forward characteristics

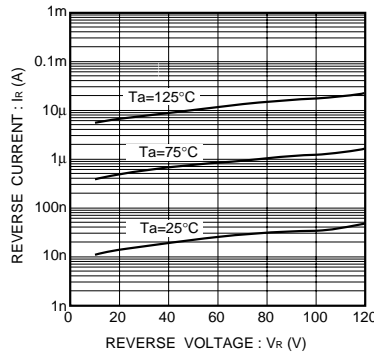


Fig.2 Reverse characteristics

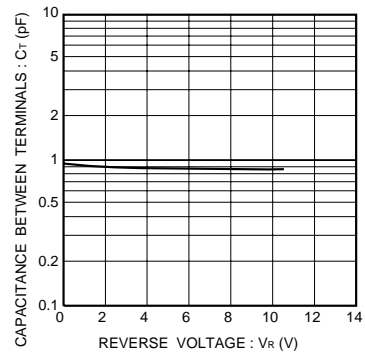


Fig.3 Capacitance between terminals characteristics

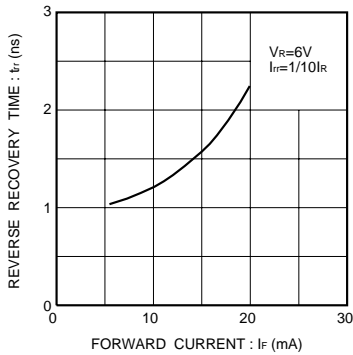


Fig.4 Reverse recovery time characteristics

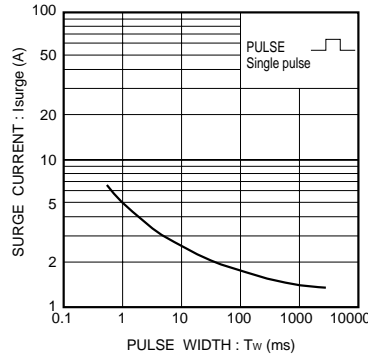


Fig.5 Surge current characteristics

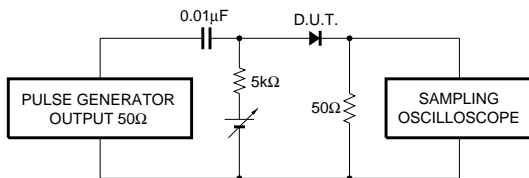
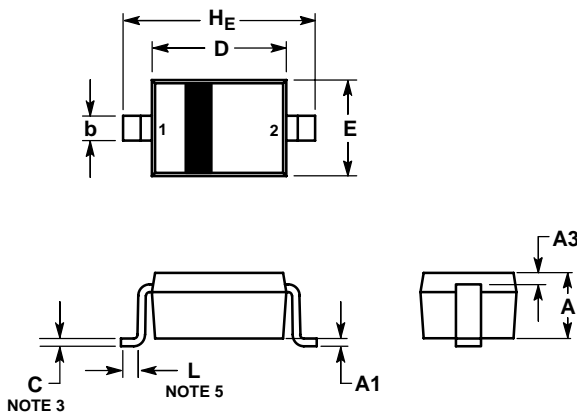


Fig.6 Reverse recovery time (t_r) measurement circuit

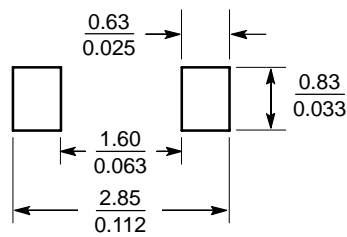
L1SS355T1G

SOD-323


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DIMENSION L IS MEASURED FROM END OF RADIUS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
C	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
E	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

SOLDERING FOOTPRINT*


X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Diodes - General Purpose, Power, Switching category:](#)

Click to view products by [Leshan manufacturer:](#)

Other Similar products are found below :

[MMBD3004S-13-F](#) [RD0306T-H](#) [DSE010-TR-E](#) [BAV17-TR](#) [BAV19-TR](#) [1N3611](#) [NTE156A](#) [NTE574](#) [NTE6244](#) [1SS181-TP](#) [1SS193,LF](#)
[1SS400CST2RA](#) [SDAA13](#) [SHN2D02FUTW1T1G](#) [LS4151GS08](#) [FC903-TR-E](#) [1N4449](#) [1N456A](#) [1N4934-E3/73](#) [1N914B](#) [1N914BTR](#)
[1SS226-TP](#) [RFUH20TB3S](#) [D291S45T](#) [BAV300-TR](#) [BAW56DWQ-7-F](#) [BAW75-TAP](#) [MM230L-CAA](#) [IDW40E65D1](#) [JAN1N3600](#) [LL4151-](#)
[GS18](#) [053684A](#) [SMMSD4148T3G](#) [707803H](#) [NSVDAN222T1G](#) [CDSZC01100-HF](#) [LL4150-M-08](#) [1N4454-TR](#) [BAV199E6433HTMA1](#)
[BAS28-7](#) [BAW56HDW-13](#) [BAS28 TR](#) [VS-HFA04SD60STR-M3](#) [NSVM1MA152WKT1G](#) [RGP30D-E3/73](#) [BAV99TQ-13-F](#) [BAS21DWA-7](#)
[NTE6250](#) [NTE582-4](#) [NTE582-6](#)